

## USB 2.0 High-Speed (480 Mbps) Signal Switch with Vbus Short Protection

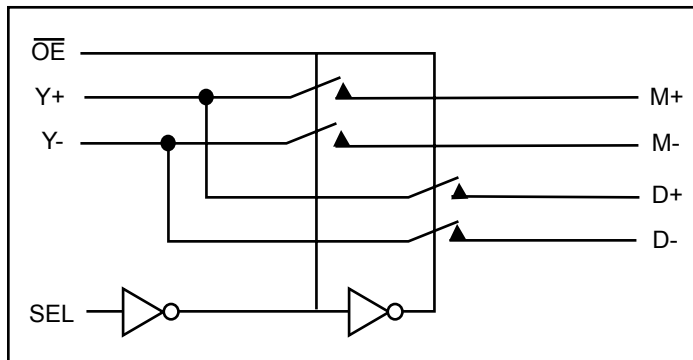
### Features

- USB 2.0 compliant (high speed and full speed)
- $R_{ON}$  is  $3.0\Omega$  typical @  $V_{DD} = 3.0V$
- Low bit-to-bit skew
- Low Crosstalk:  $-33dB$  @ 480 Mbps
- Off Isolation:  $-30dB$  @ 480 Mbps
- Near-Zero propagation delay: 250ps
- Channel On Capacitance: 6.0pF (typ)
- $V_{DD}$  Operating Range: 3.0V to 3.6V
- Data pin I/O ESD (pins 1, 2, 4, 5, 6, and 7):  $\pm 4kV$  contact per IEC61000-4-2 spec
- $-3dB$  BW of 1400MHz
- I/O pins have over-voltage protection and can tolerate a short to Vbus
- Packaging (Pb-free & Green):
  - 10-contact TQFN, 1.3mm x 1.6mm x 0.75mm (ZL10)

### Application

- Routes signals for USB 2.0
- Hand-held devices

### Block Diagram



### Truth Table

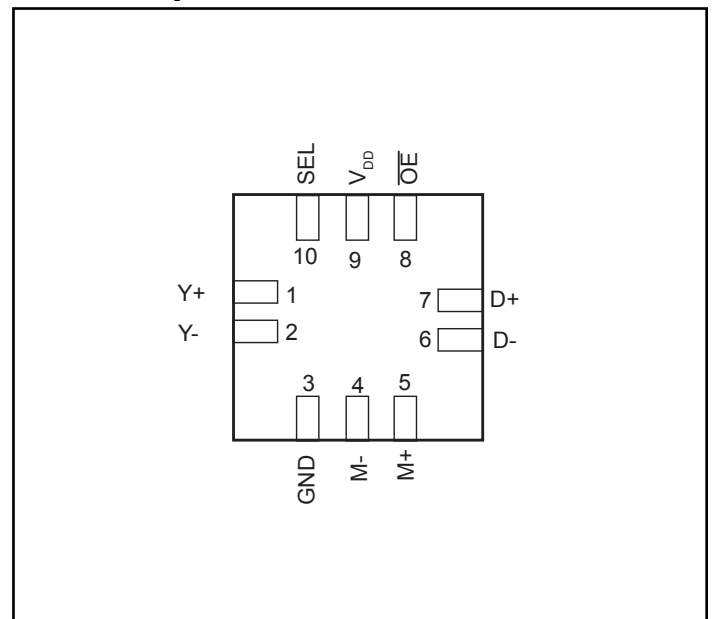
SEL	$\overline{OE}$	Y+	Y-
X	H	Hi-Z	Hi-Z
L	L	M+	M-
H	L	D+	D-

### Description

The PI3USB103 is a single differential channel 2:1 multiplexer/demultiplexer USB 2.0 Switch. Industry leading advantages include a propagation delay of less than 250ps, resulting from its low channel resistance and I/O capacitance. The device multiplexes differential outputs from a USB Host device to one of two corresponding outputs. The switch is bidirectional and offers little or no attenuation of the high-speed signals at the outputs. It is designed for low bit-to-bit skew, high channel-to-channel noise isolation and is compatible with various standards, such as High Speed USB 2.0 (480 Mb/s).

The PI3USB103 offers over voltage protection per the USB 2.0 specification. With the chip powered on or off, all I/O pins can withstand a short to Vbus. If  $V_{DD} = 0V$ , the I/Os can still have signals present, and the signal will NOT leak through to  $V_{DD}$ .

### Pin Description



## Maximum Ratings

(Above which useful life may be impaired. For user guidelines, not tested.)

Storage Temperature .....	-65°C to +150°C
Supply Voltage to Ground Potential .....	-0.5V to +4.0V
DC Input Voltage .....	-0.5V to +7V
DC Output Current .....	120mA
Power Dissipation .....	0.5W

**Note:** Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## DC Electrical Characteristics for USB 2.0 Switching over Operating Range

( $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ ,  $V_{DD} = 3.0 - 3.6\text{V}$ )

Parameter	Description	Test Conditions <sup>(1)</sup>		Min.	Typ. <sup>(2)</sup>	Max.	Units
$V_{IH}$	Input HIGH Voltage	Guaranteed HIGH level	$V_{DD} = 3.3\text{V}$	1.3		$V_{DD}$	V
$V_{IL}$	Input LOW Voltage	Guaranteed HIGH level		GND		0.6	
$V_{IK}$	Clamp Diode Voltage	$V_{DD} = \text{Max.}, I_{IK} = -18\text{mA}$				-1.2	
$I_{IH}$	Input HIGH Current	$V_{DD} = \text{Max.}, V_{IH} = V_{DD}$				$\pm 5$	$\mu\text{A}$
$I_{IL}$	Input LOW Current	$V_{DD} = \text{Max.}, V_{IL} = \text{GND}$				$\pm 5$	
$R_{ON}$	Switch On-Resistance for USB 2.0 HS signal <sup>(3)</sup>	$V_{DD} = \text{Min.}, -0.4\text{V} \leq V_{\text{input}} \leq 1.0\text{V}, I_{ON} = -40\text{mA}$			3.0	5.0	$\Omega$
$R_{ON}$	Switch On-Resistance for USB FS signal	$V_{DD} = \text{min.}, 0\text{V} \leq V_{\text{input}} \leq 3.3\text{V}$				9	
$R_{ON}$	Switch On-Resistance for MHL signal	$V_{DD} = \text{min.}, 2\text{V} \leq V_{\text{input}} \leq 3.3\text{V}$				9	
$R_{ON(\text{flat})}$	On-resistance flatness	$V_{DD} = \text{min.}, -0.4\text{V} \leq V_{\text{input}} \leq 1.0\text{V}$			0.15	0.5	
$\Delta R_{ON}$	On-Resistance match from center ports to any other port <sup>(3)</sup>	$V_{DD} = \text{Min.}, -0.4\text{V} \leq V_{\text{input}} \leq 0.4\text{V}, I_{ON} = -40\text{mA}$			0.9	2.0	
$I_{OZ}$	I/O leakage current when port is off	$V_{DD} = 3.6\text{V}, V_{\text{input}} = 0 \text{ to } 3.6\text{V}, \text{switch} = \text{off}, \text{OE} = \text{HIGH}$				$\pm 2$	$\mu\text{A}$
$I_{OFF}$	Signal leakage when chip is off	$V_{DD} = 0\text{V}, V_{\text{input}} = 0 \text{ to } 7\text{V}$				$\pm 10$	$\mu\text{A}$

### Notes:

- For max. or min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- $V_{DD} = 3.0 - 3.6\text{V}$ ,  $T_A = 25^\circ\text{C}$  ambient and maximum loading.
- Measured by the voltage drop between D and  $D_n$  pin at indicated current through the Switch On-Resistance is determined by the lower of the voltages on the two (D,  $D_n$ ) pins.

## Power Supply Characteristics ( $V_{DD} = 3.0 - 3.6\text{V}$ )

Parameters	Description	Test Conditions <sup>(1)</sup>		Min.	Typ.	Max.	Units
$I_{CC}$	Power Supply Current	$V_{DD} = \text{Max.}, V_{SEL} = \text{GND or } V_{DD}, \overline{\text{OE}} = \text{LOW}$				75	$\mu\text{A}$
		$V_{DD} = \text{Max.}, V_{SEL} = 1.5\text{V} - 2.1\text{V}$ ,				100	$\mu\text{A}$
$I_{CCq}$	Quiescent Power Supply Current	$V_{DD} = 3.3\text{V}, V_{SEL} = \text{GND or } V_{DD}$ ,				6	$\mu\text{A}$
		$V_{DD} = 3.3\text{V}, V_{SEL} = 1.5\text{V} - 2.1\text{V}$ ,				8	$\mu\text{A}$

### Notes:

- For max. or min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.

**Capacitance ( $T_A = 25^\circ\text{C}$ ,  $f = 1\text{MHz}$ )**

Parameters <sup>(3)</sup>	Description	Test Conditions <sup>(1)</sup>	Typ. <sup>(2)</sup>	Max.	Units
$C_{IN}$	Input Capacitance	$V_{SEL} = 0\text{V}$	2.7	3.0	pF
$C_{OFF}$	Switch Capacitance, Switch OFF		2.8	3.0	
$C_{ON}$	Switch Capacitance, Switch ON		6.0	6.5	

**Dynamic Electrical Characteristics Over the Operating Range**

Parameters	Description	Test Conditions	Min.	Typ. <sup>(2)</sup>	Max.	Units
$X_{TALK}$	Crosstalk	$R_L = 50\Omega$	$f = 240\text{ MHz}$	-35	-39	dB
			$f = 825\text{ MHz}$	-25	-28	
$O_{IRR}$	OFF Isolation	$R_L = 50\Omega$	$f = 240\text{ MHz}$	-29	-32	dB
			$f = 825\text{ MHz}$	-20	-23	
BW	-3dB Bandwidth	$R_L = 50\Omega$	1100	1400		MHz
BW	-0.5dB Bandwidth	$R_L = 50\Omega$	150	400		MHz
IN	Insertion Loss	$f = 240\text{ MHz}$		0.47	0.67	dB
		$f = 825\text{ MHz}$		1.8	2.4	
		$f = 1.0\text{ GHz}$		2.2	2.6	
		$f = 1.125\text{ GHz}$		2.4	3.0	

**Notes:**

- For max. or min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- Typical values are at  $V_{DD} = 3.3\text{V}$ ,  $T_A = 25^\circ\text{C}$  ambient and maximum loading.
- This parameter is determined by device characterization but is not production tested.

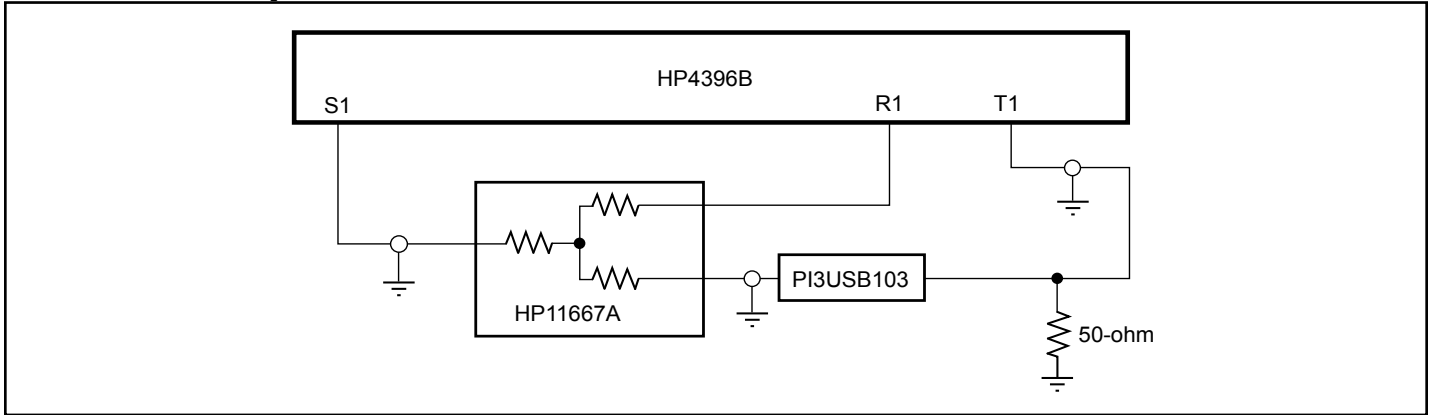
**Switching Characteristics**

Parameters	Description	Test Conditions <sup>(1)</sup>	Min.	Typ.	Max.	Units
$t_{PD}$	Propagation Delay <sup>(2,3)</sup>	See Test Circuit for Electrical Characteristics		0.25	0.35	ns
$t_{PZH}$ , $t_{PZL}$	Line Enable Time - SEL, $\overline{OE}$ to D(+/-), M(+/-)		0.5		60	
$t_{PHZ}$ , $t_{PLZ}$	Line Disable Time - SEL, $\overline{OE}$ to D(+/-), M(+/-)		0.5		60	
$t_{SKC-C}$	Output skew, channel-to-channel <sup>(2)</sup>			3.5	14	ps

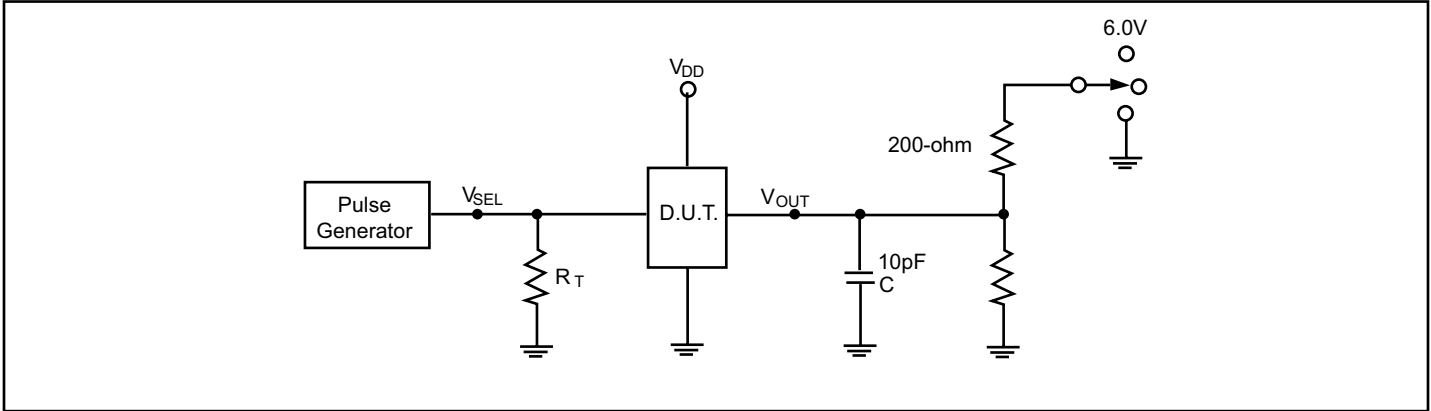
**Notes:**

- For max. or min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- Guaranteed by design.
- The switch contributes no propagational delay other than the RC delay of the On-Resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25ns for 10pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagational delay to the system. Propagational delay of the switch when used in a system is determined by the driving circuit on the driving side of the switch and its interactions with the load on the driven side.

**Test Circuit for Dynamic Electrical Characteristics**



**Test Circuit for Electrical Characteristics**



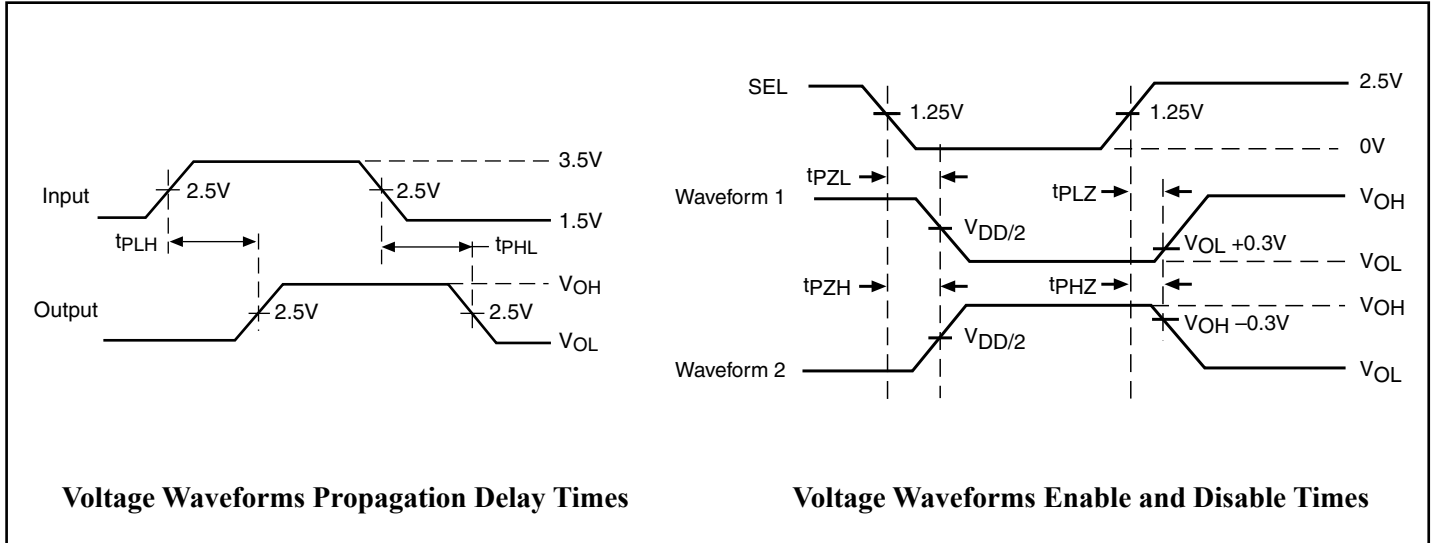
**Notes:**

- $C_L$  = Load capacitance: includes jig and probe capacitance.
- $R_T$  = Termination resistance: should be equal to  $Z_{OUT}$  of the Pulse Generator
- All input impulses are supplied by generators having the following characteristics:  $PRR \leq \text{MHz}$ ,  $Z_O = 50\Omega$ ,  $t_r \leq 2.5\text{ns}$ ,  $t_f \leq 2.5\text{ns}$ .
- The outputs are measured one at a time with on transition per measurement.

**Switch Positions**

Test	Switch
$t_{PLZ}$ , $t_{PZL}$	6.0V
$t_{PHZ}$ , $t_{PZH}$	GND
Prop Delay	Open

## Switching Waveforms



## Applications Information

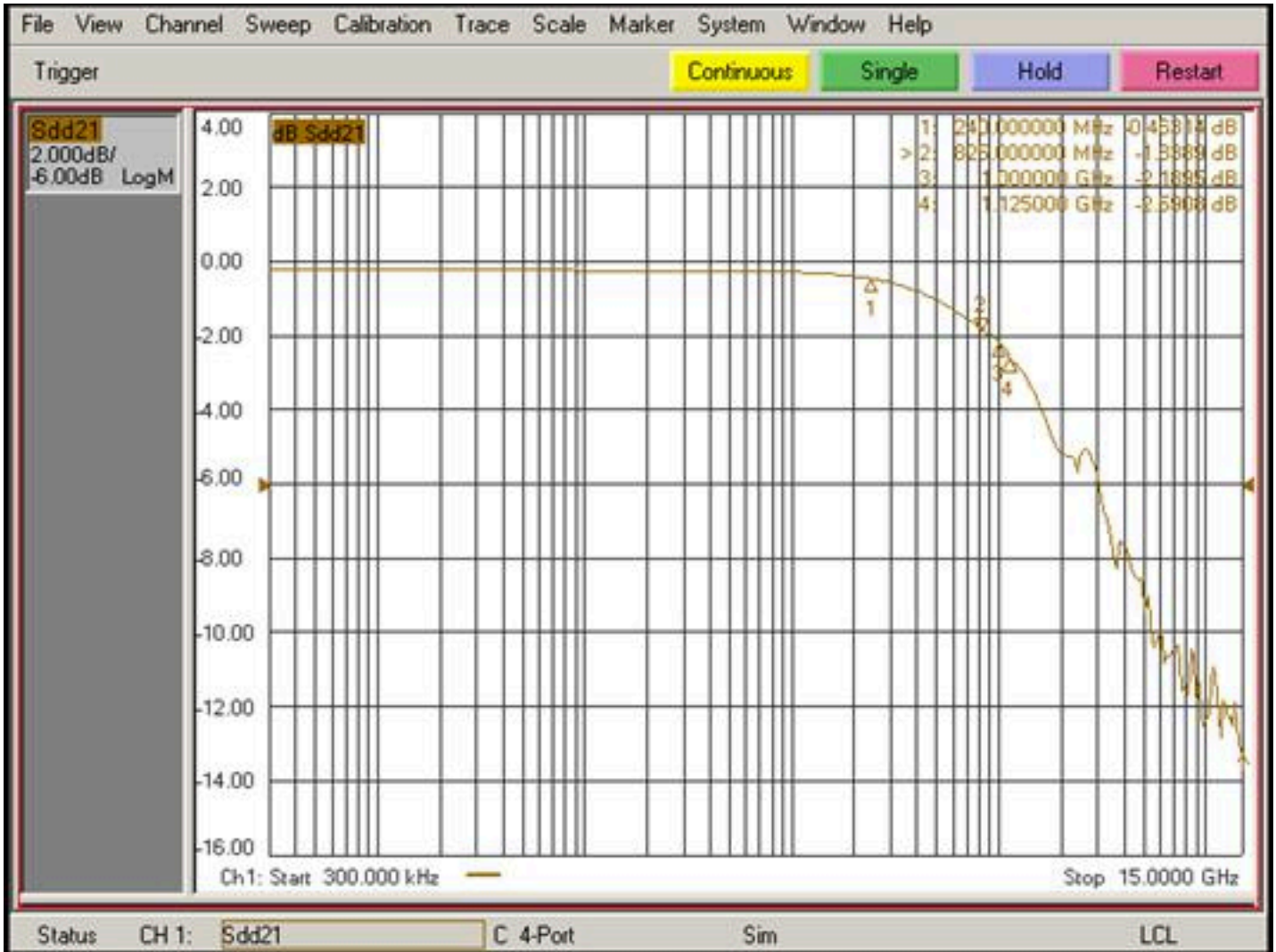
### Logic Inputs

The logic control inputs can be driven up to +3.6V regardless of the supply voltage. For example, given a +3.3V supply, the output enables or select pins may be driven low to 0V and high to 3.6V. Driving IN Rail-to-Rail® minimizes power consumption.

### Power Supply Sequencing

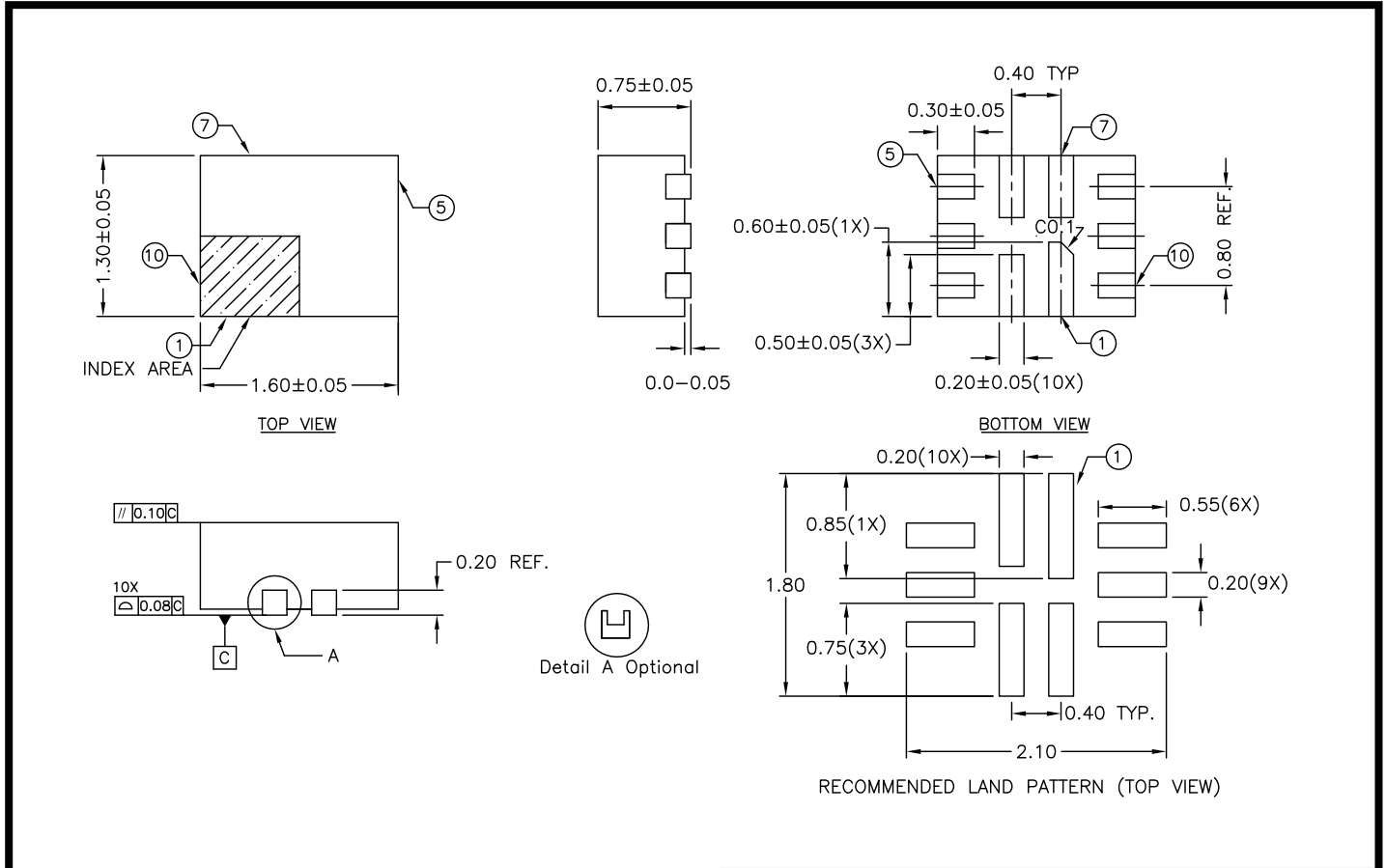
Since this product does not contain any PMOS parasitic at the I/O pins, proper supply sequencing is not required.

*Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd.*



**Differential Insertion loss,  $V_{DD} = 3.3V$**

**Packaging Mechanicals: 10-Contact TQFN (ZL10)**



NOTE :

1. ALL DIMENSIONS ARE IN MILLIMETERS.
2. REFER MO-220.
3. RECOMMENDED LAND PATTERN IS FOR REFERENCE ONLY.

	DATE: 08/30/13
DESCRIPTION: 10-Contact, Thin Fine Pitch Quad Flat No-Lead (TQFN)	
PACKAGE CODE: ZL (ZL10)	
DOCUMENT CONTROL #: PD-2052	REVISION: E

13-0175

**Ordering Information**

Ordering Code	Package Code	Package Description	Top Mark
PI3USB103ZLE	ZL	10-contact, Thin Fine Pitch Quad Flat No-Lead (TQFN)	CW

Notes:

- Thermal characteristics can be found on the company web site at [www.pericom.com/packaging/](http://www.pericom.com/packaging/)
- E = Pb-free and Green
- Adding X suffix = Tape/Reel